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April 1st, 2010
Renesas Electronics Corporation

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H8/300L Series

Interfacing the H8/3644 with an EEPROM

Introduction

Figure 1.1 shows the one-to-one interface between the H8/3644 and EEPROM (HN58X2408) which are connected via a serial clock line (SCL) and a serial data line (SDA).

Target Device

H8/3644

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1. Specifications

1. Figure 1.1 shows the one-to-one interface between the H8/3644 and EEPROM (HN58X2408) which are connected via a serial clock line (SCL) and a serial data line (SDA).
2. Data in ROM is written to EEPROM, and the data written in the EEPROM is read in RAM again.
3. Data to be transferred is a program for turning on an LED connected to the port 7₃.
4. Data is transferred in LSB first.

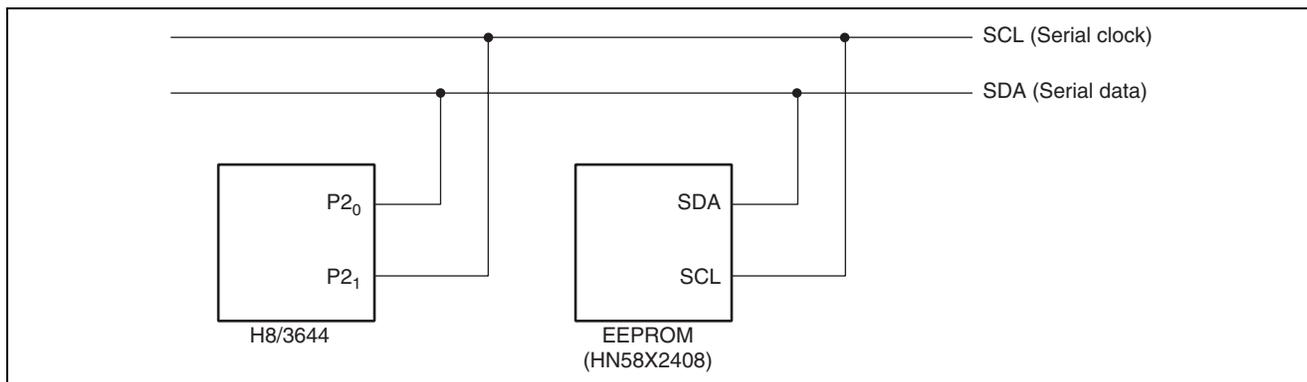


Figure 1.1 Connection between the H8/3644 and EEPROM

2. Concept

1. Figure 2.1 shows EEPROM (HN58X2408) bus timing to be used in this sample task.

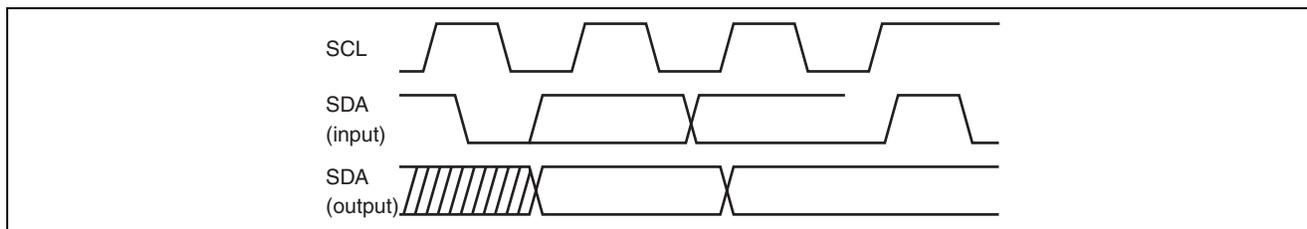


Figure 2.1 EEPROM (HN58X2408) Bus Timing

2. In this sample task, a serial clock to be output from the SCL is generated by setting the P2₁ pin level to either high or low through software processing with the bus timings for EEPROM to be used as shown in figure 2.2. The h8/3644 interfaces with the EEPROM (HN58X2408) by outputting/inputting serial data from the pin P2₀ synchronized with the serial clock generated through software processing. Figure 2.2 shows pins P2₁ and P2₀ timing waveforms.

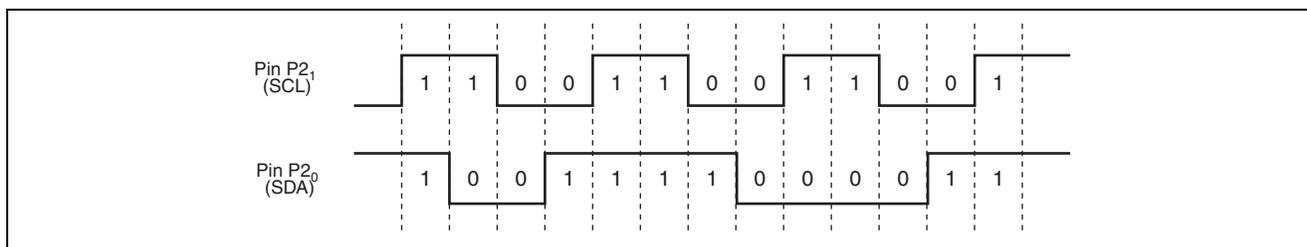


Figure 2.2 Pins P2₁ and P2₀ Timing Waveforms

3. Description of Functions

- In this sample task, the H8/3644 interfaces with EEPROM (HN58X2408) through connection as shown in figure 3.1. Table 3.1 shows the pin description of EEPROM (HN58X2408).

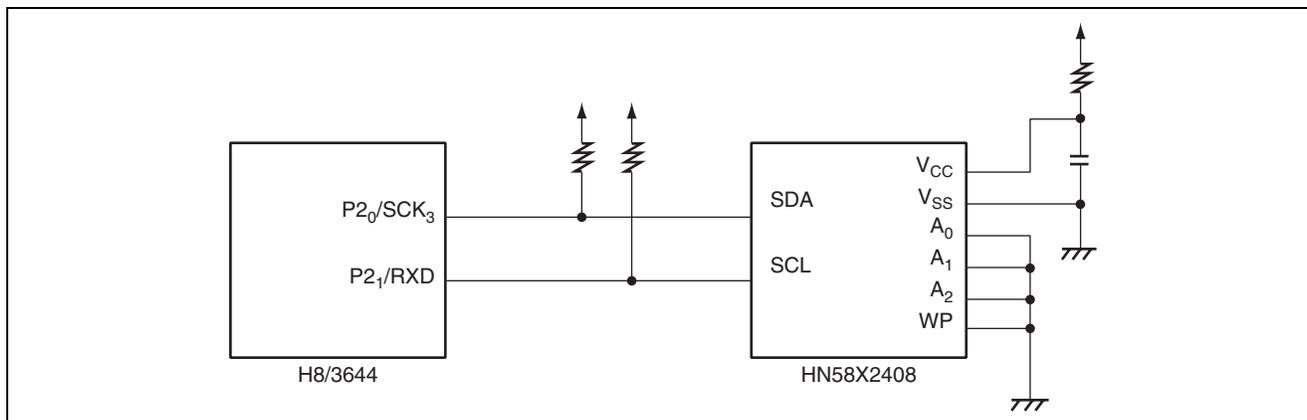


Figure 3.1 Connection between the H8/3644 and HN58X2408

Table 3.1 HN58X2408 Pin Description

Pin Name	Description
A0 to A2	Device address
SCL	Serial clock input
SDA	Serial data input/output
WP	Write protect
V _{CC}	Vcc
V _{SS}	GND

- The H8/3644 interfaces with EEPROM (HN58X2408) with the configuration of the block diagram as shown in figure 3.2. The functions of the H8/3644 are described below.
 - The port 2 is a three-bit input/output port, which has three pins, P2₀/SCK₃, P2₁/RXD, and P2₂/TXD.
 - The pin P2₀/SCK₃ is used as a serial data input/output pin by connecting to the SDA pin of the HN58X2048.
 - The pin P2₁/RXD is used as a serial clock output pin by connecting to the SCL pin of the HN58X2048.
 - The port 7 is a five-bit input/output port, which has five pins, P7₃, P7₄/TMRIV, P7₅/TCIV, P7₆/TMOV, and P7₇.
 - The pin P7₃ is used as an output pin to the LED.
 - The pin P2₀/SCK₃ functions as a P2₀ input/output pin by setting the clock enable 1 (CKE1) and the clock enable 0 in the serial control register 3 (SCR3) and the communication mode (COM) in the serial mode register (SMR) to all 0. The pin P2₀/SCK₃ functions as a P2₀ input pin when the port control register 2₀ (PCR2₀) in the port control register 2 (PCR2) is set to 0, or functions as a P2₀ output pin when PCR2₀ is set to 1.
 - The pin P2₁/RXD functions as a P2₁ input/output pin by setting the receive enable (RE) in SCR3 to 0. The pin P2₁/RXD functions as a P2₁ input pin when the port control register 2₁ (PCR2₁) in PCR2 is set to 0, or functions as a P2₁ output pin when PCR2₁ is set to 1.
 - The pin P7₃ functions as a P7₃ output pin by setting the port control register 7₃ (PCR7₃) in the port control register 7 (PCR7) to 1.

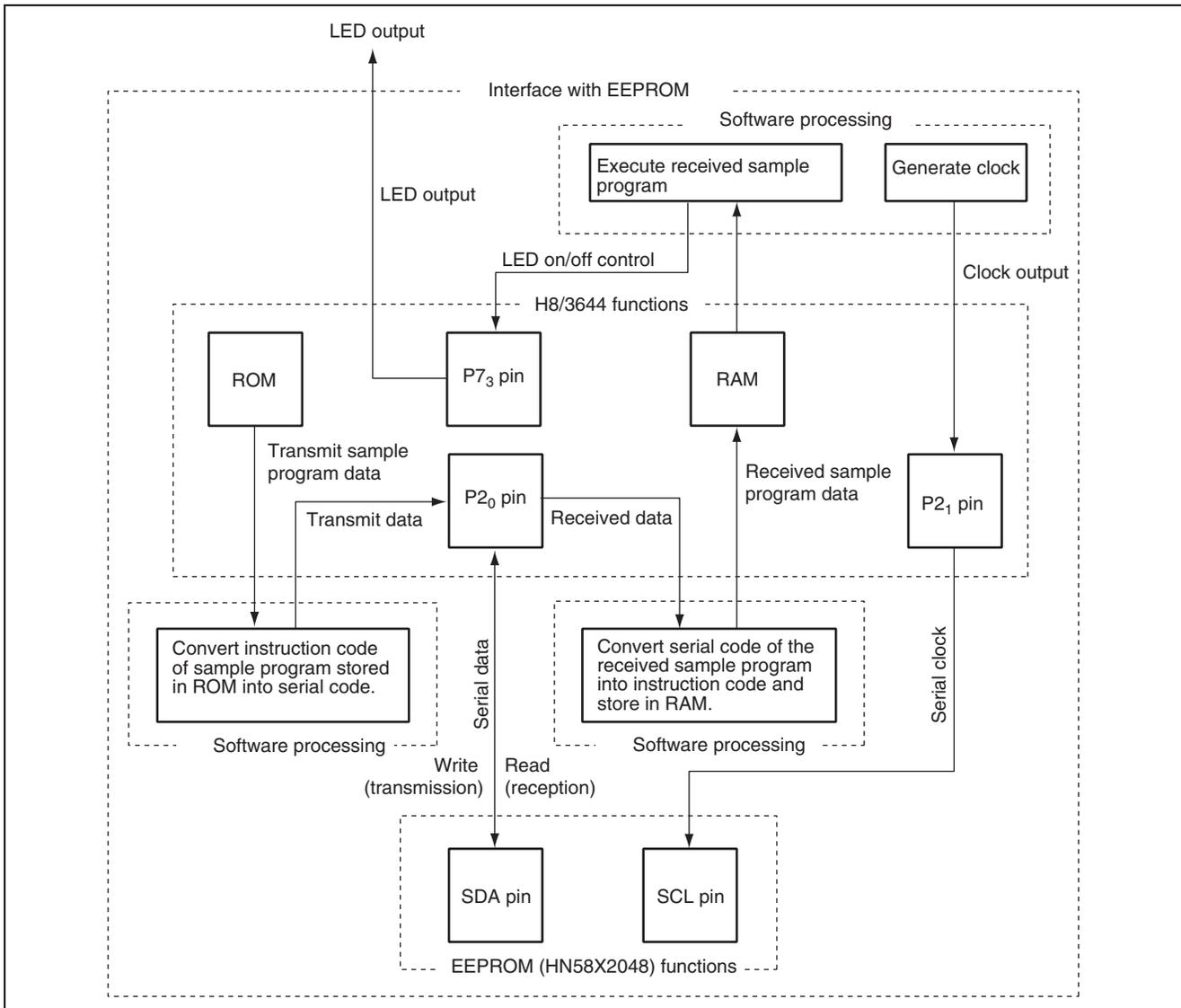


Figure 3.2 Block Diagram of Interface with EEPROM (HN58X2048)

3. Table 3.2 shows function allocations of this sample task. The H8/3644 interfaces with EEPROM through the H8/3644 function allocations as shown in table 3.2.

Table 3.2 H8/3644 Function Allocation

Function	Function Allocation
Pin P2 ₀	Inputs/outputs serial data
P2 ₀	Stores data from the pin P2 ₀
PCR2 ₀	Sets P2 ₀ input/output pin functions
Pin P2 ₁	Serial clock output
P2 ₁	Stores data from the pin P2 ₁
PCR2 ₁	Sets P2 ₁ input/output pin functions
Pin P7 ₃	Outputs LED
P7 ₃	Stores data from the pin P7 ₃
PCR7 ₃	Sets P7 ₃ input/output pin functions

4. Specifications of the EEPROM (HN58X2048) used in this sample task are described below.
 - A. The EEPROM (HN58X2048) used in this sample task is two-wired serial interface electrically rewritable ROM (EEPROM), which employs the latest NMOS memory technology, CMOS process, and low-voltage circuit technology and allows operation at low power supply voltage, low power consumption, high-speed operation, and high reliability. High-speed data rewriting is performed through a 32-byte page rewriting function.
 - B. Features of the EEPROM (HN58X2048) used in this sample task are shown below.
 - Single power supply: 1.8 to 5.5 V
 - Two-wired serial interface
 - Operating frequency: 400 kHz
 - Current consumption
 - During standby: 3 μ A (max.)
 - During reading: 1 mA (max.)
 - During rewriting: 3 mA (max.)
 - Page rewriting: 32-byte page size
 - Rewriting time: 10 ms (2.7 V or greater)/15 ms (1.8 to 2.7 V)
 - Number of rewriting times: 10^5 (during page rewriting)
 - C. For starting read/write operation, a start condition must be set by switching the SDA input from high to low during a SCL input high. For stopping read/write operation, a stop condition must be set by switching the SDA input from low to high during a SCL input high. In the case of read operation, when the stop condition is input, EEPROM ends read operation and enters standby state. In the case of write operation, when the stop condition is input, input cycle of data to be written ends, EEPROM enters standby state once data is written in memory during a rewrite cycle (t_{wc}). Figure 3.3 shows start condition/stop condition set timings.

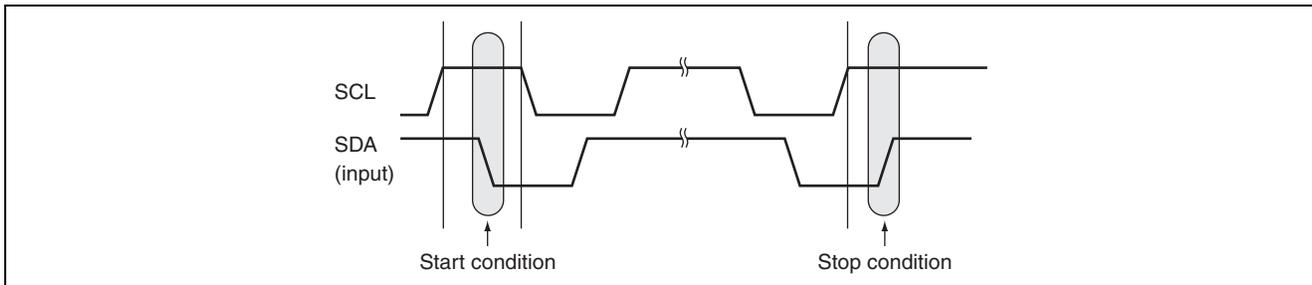


Figure 3.3 Start Condition/Stop Condition Set Timings

D. Serial data such as address information and read information is transferred in 8-bit units. The acknowledge signal is used to indicate that this 8-bit data has been received or transmitted successfully. The reception side outputs 0 at the ninth SCL clock. The transmission side releases the bus mastership to receive the acknowledge signal at the ninth clock. During write operation, the EEPROM receives data, that is, the EEPROM outputs 0, that is, the acknowledge signal at the ninth clock when all 8-bit data have been received. During read operation, the EEPROM outputs 0 of the acknowledge signal after receiving 8-bit data following the start condition. Following this, the EEPROM outputs read data in 8-bit units, then releases the bus mastership, and waits for being transferred 0 of the acknowledge signal. When 0 of the acknowledge signal is detected, the EEPROM outputs data to be read at the next address. When 0 of the acknowledge signal is not detected and the stop condition is received, the EEPROM ends read operation and enters standby state. Note that when 0 of the acknowledge signal is not detected and the stop condition is not transmitted, the EEPROM does not output any data and keeps the bus mastership release state. Figure 3.4 shows the acknowledge signal output timings.

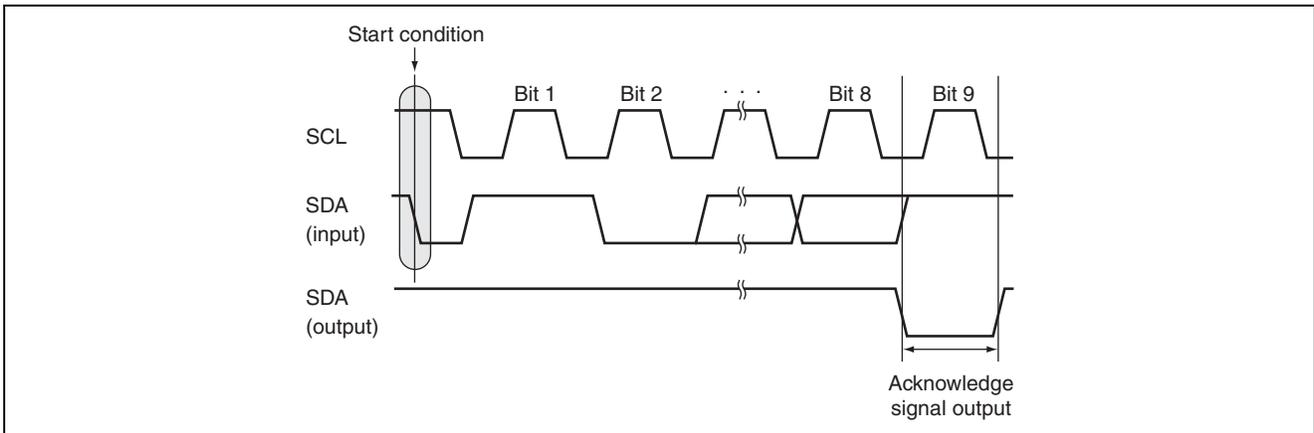


Figure 3.4 Acknowledge Signal Output Timings

E. An 8-bit device address word is input following the starting condition signal to initiate read/write operation of a device. The device address words include a 4-bit device code, a 3-bit device address code, and a 1-bit read/write code. Upper 4 bits of the device address words are device codes used for identifying a device type, which are fixed to '1010' in the EEPROM (HN58X2408) used in this sample task. Following the device codes, the 3-bit device address code is input in order of A2, A1, and A0. The device address codes are used for selecting a device from up to 8 devices connected to the bus. The device address codes in the EEPROM (HN58X2408) used in this sample task are set to '000'. The eighth bit of the device address words is a R/W code, which is used to switch read/write operation. When 0 is input, the EEPROM performs write operation, or when 1 is input, the EEPROM performs read operation. Note that when the device codes are not set to '1010', or when the device address codes do not match, the EEPROM does not perform read/write operation, but enters standby mode. Figure 3.5 shows the device address words.

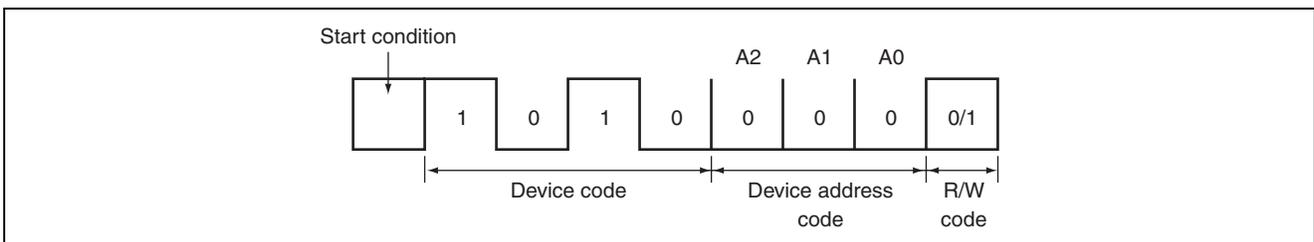


Figure 3.5 Device Address Words

F. In this sample task, a page-write function for rewriting an arbitrary number of bytes up to 32 bytes at once is used to perform write operation. The start condition, the device address words, the memory addresses (n), and write data (Dn) are input in that order while confirming 0 output of the acknowledge signal for each of 9 bits. When write data (Dn + 1) is input, the EEPROM enters page write mode. When the write data (Dn + 1) is input, addresses in the page (a0 through a4) are automatically incremented by 1 to an address (n + 1). In this manner, write data can be input sequentially, addresses in the page are incremented for each write data input, as a result, up to 32 bytes of write data can be input. When the addresses in the page (a0 through a4) reach the last address in the page, the address is rolled over and is returned to the start address of the page. When roll over occurs, write data is input twice or more to the same address, however, the latest input write data is effective. When the stop condition is input, write data input ends and the EEPROM starts rewrite operation. Figure 3.6 shows the page write operation.

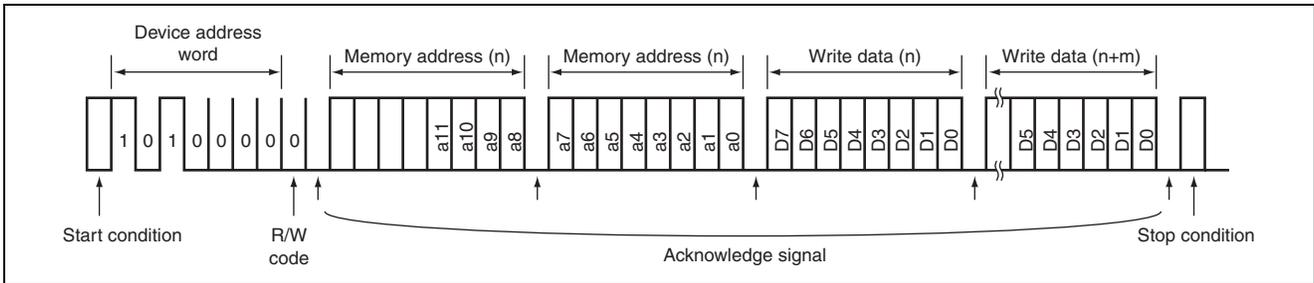


Figure 3.6 Page Write Operation

G. Acknowledge polling is a function to determine whether or not EEPROM is being rewritten. An 8-bit device address word is input following the start condition during rewrite cycle. In the case of the acknowledge polling, read/write code may be set to any of 1 or 0. The acknowledge signal at the ninth bit is used to determine whether or not EEPROM is being rewritten. When the acknowledge signal is 1, EEPROM is being rewritten, or when the acknowledge signal is 0, rewrite cycle ends. The acknowledgement polling starts functioning when the stop condition is input after data to be written is input.

H. In this sample task, the EEPROM performs read operation using sequential read mode for reading data sequentially. To begin with, the start address of data to be read in dummy write mode is input. When 0 of the acknowledge signal is input after outputting 8-bit data, an address is incremented by 1, and the next 8-bit data is output. When 0 of the acknowledge signal is input continuously after outputting data, data is sequentially output while incrementing the address by 1. When address reaches the last address, address is rolled over to address 0. Sequential read is possible after roll over. To stop operation, 1 of the acknowledge signal (alternatively release of the bus mastership without inputting the acknowledge signal) and the stop condition should be input in that order. Figure 3.7 shows the sequential read operation.

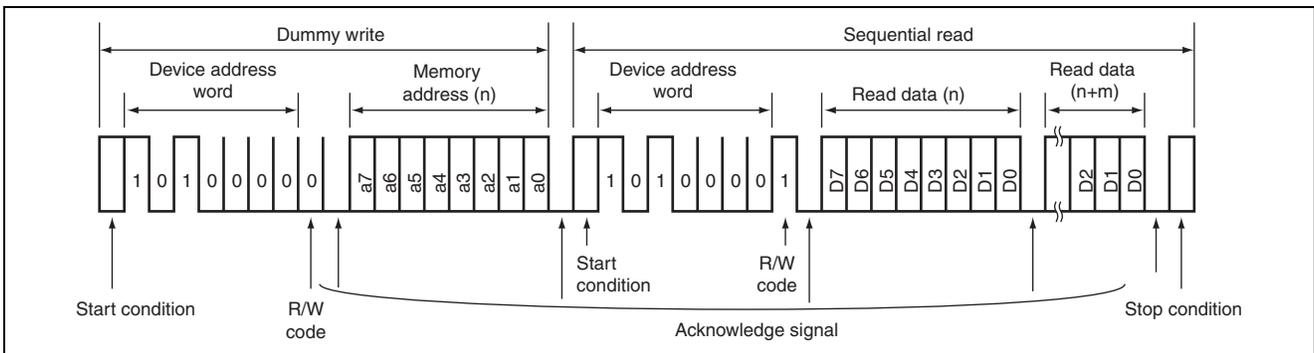


Figure 3.7 Sequential Read Operation

- I. EEPROM should wait during rewrite cycle (t_{wc}) for entering read operation after write operations end. The rewrite cycle (t_{wc}) is 10 ms (max.) during 5-V operation. Figure 3.8 shows rewrite cycle timings.

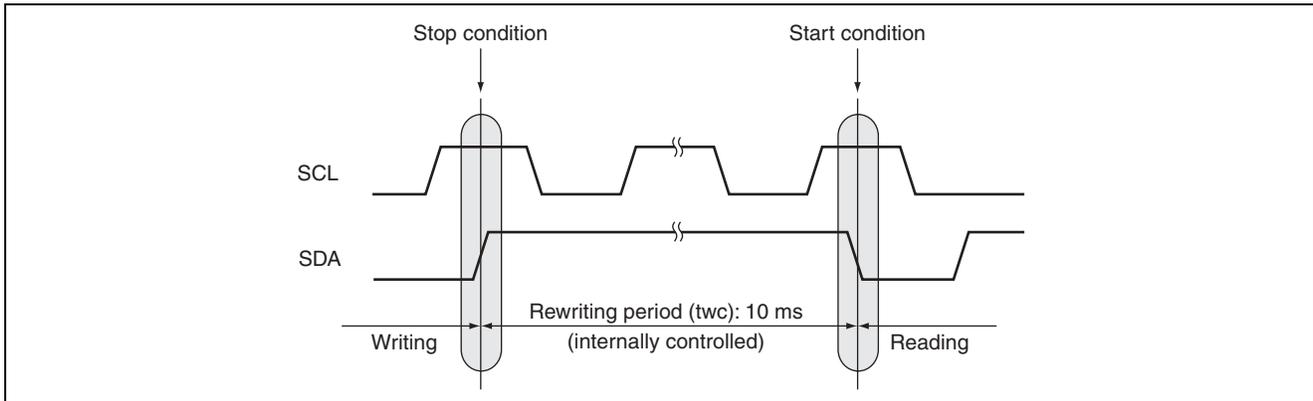


Figure 3.8 Rewrite Cycle Timings

4. Principles of Operation

1. Figure 4.1 illustrates the principle of operation of this sample task. As shown in figure 4.1, data a rewritten (transmitted) to EEPROM through the H8/3644 hardware processing and software processing.

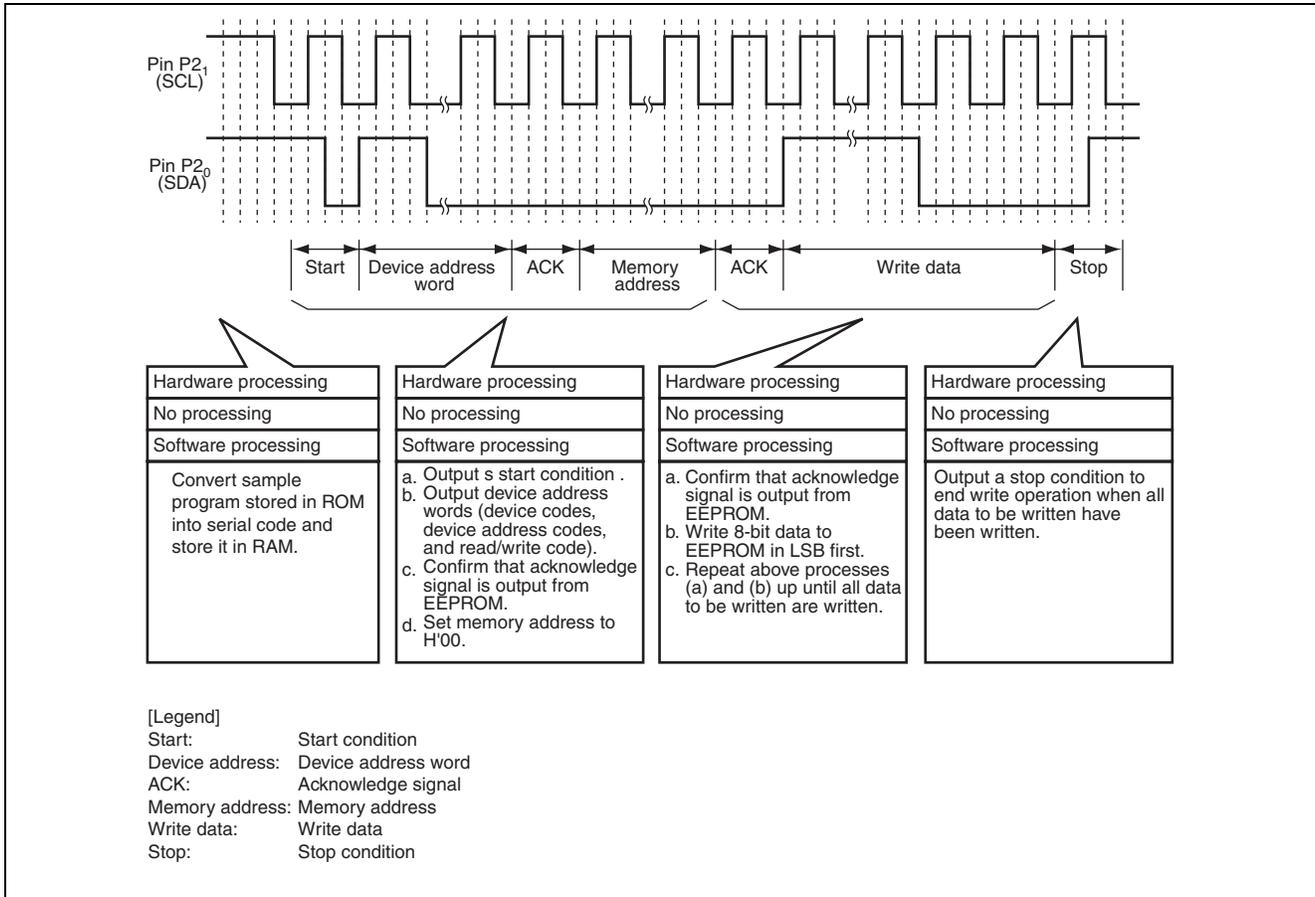


Figure 4.1 Principle of Operation during Writing to EEPROM

2. Figure 4.2 shows the principle of operation during read operation (reception). As shown in figure 4.2, data is read (received) from EEPROM through the H8/3644 hardware/software processing.

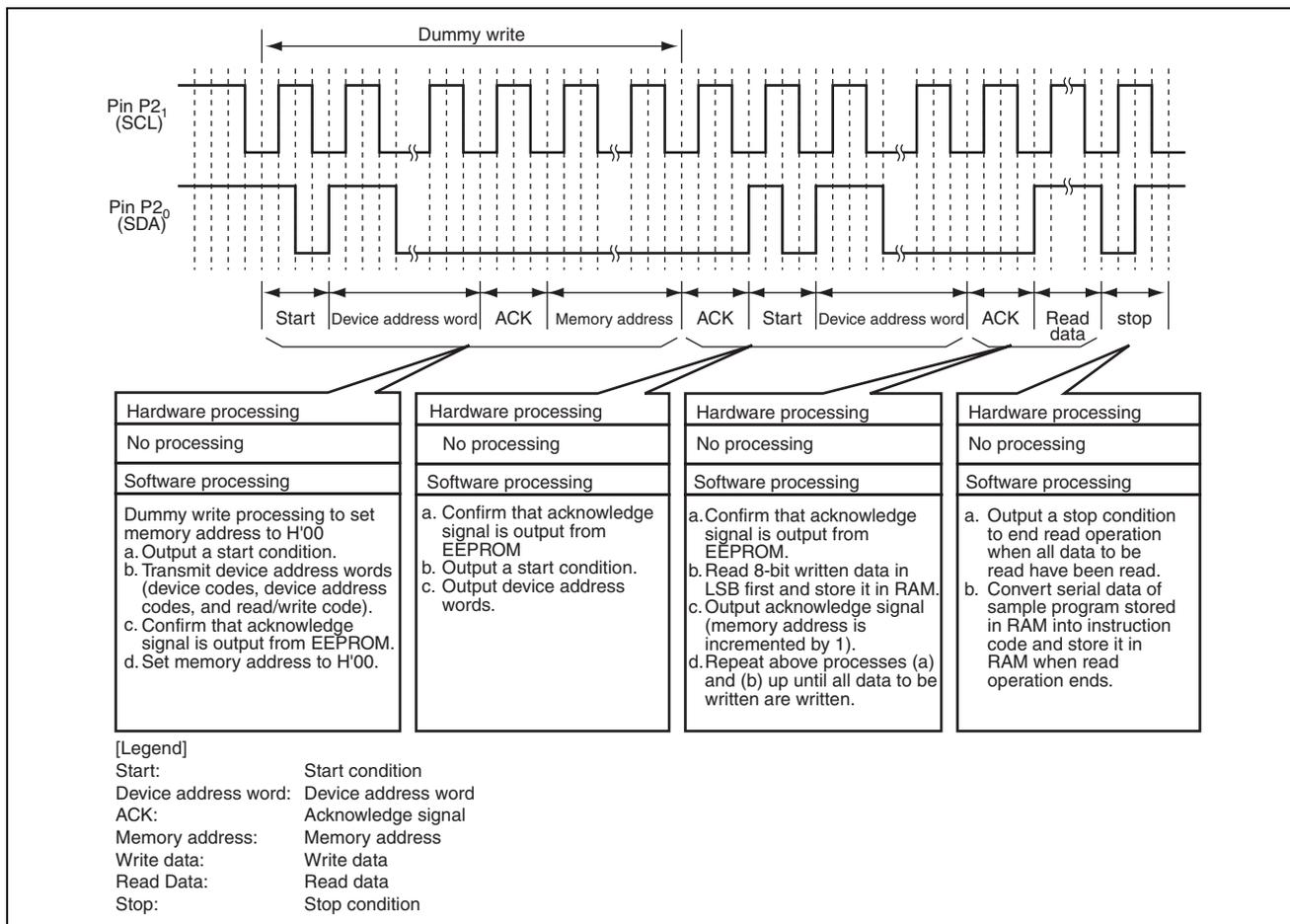


Figure 4.2 Principle of Operation during Reading from EEPROM

3. Table 4.1 shows input/output operation to/from the port 2 used in this sample task. Through settings as shown in table 4.1, the serial clock is output and serial data is input/output.

Table 4.1 P2₁ (SCL) and P2₀ (SDA) Input/Output Settings

Pin setting	Output value	P2 ₁ (SCL) = 1	P2 ₁ (SCL) = 1	P2 ₁ (SCL) = 0	P2 ₁ (SCL) = 0
		P2 ₀ (SDA) = 1	P2 ₀ (SDA) = 0	P2 ₀ (SDA) = 1	P2 ₀ (SDA) = 0
PDR2	P2 ₁	0	0	0	0
	P2 ₀	0	0	0	0
PCR2	PCR2 ₁	0 (input pin function)	0 (input pin function)	1 (output pin function)	1 (output pin function)
	PCR2 ₀	0 (input pin function)	1 (output pin function)	0 (input pin function)	1 (output pin function)

4. Figure 4.3 shows the H8/3644 memory map used in this sample task.

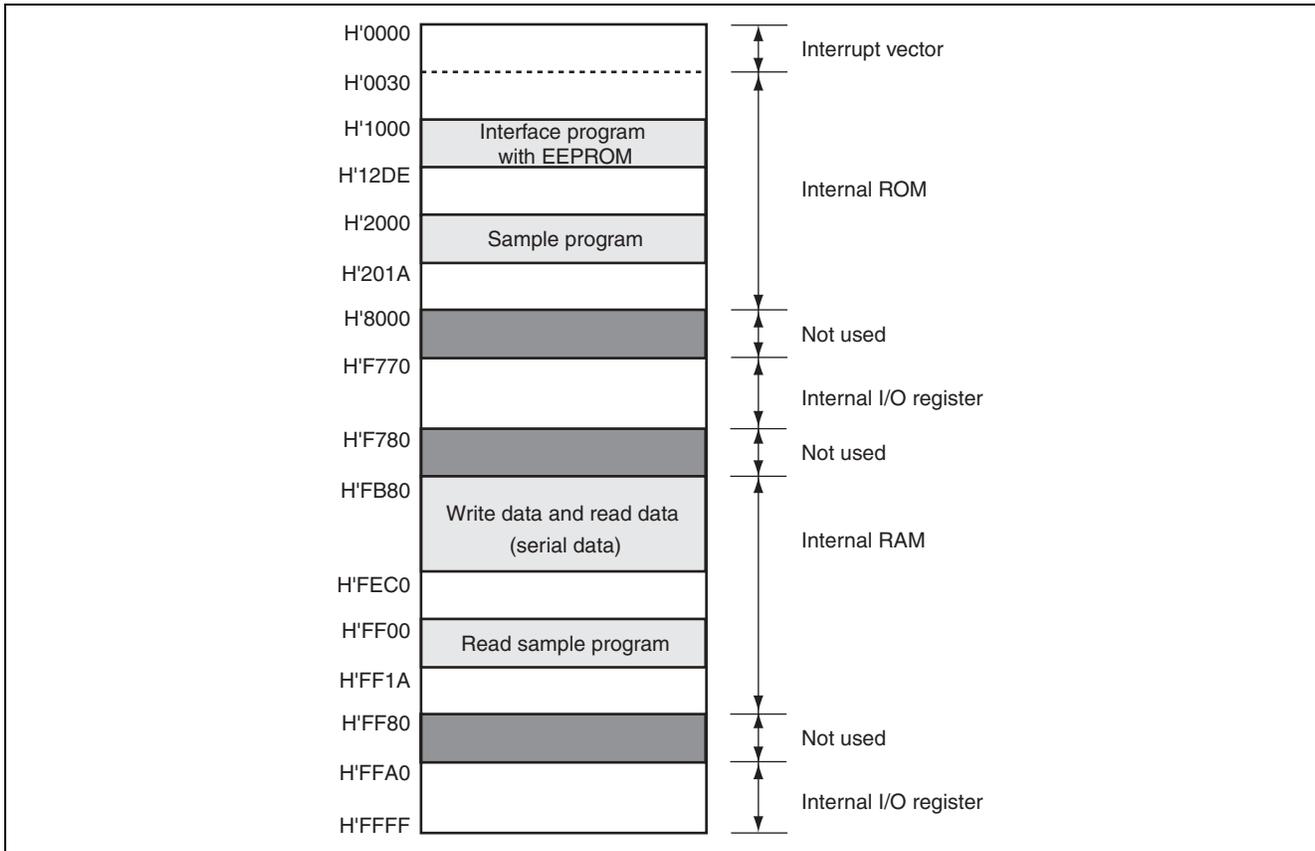


Figure 4.3 H8/3644 Memory Map used in this Sample Task

5. Description of Software

5.1 Modules

Table 5.1 describes the modules used in this sample task.

Table 5.1 Description of Modules

Module	Label	Function
Main routine	MAIN	Initializes stack pointer, disables interrupt, initializes RAM to be used, waits during rewrite cycle, and controls read/write from/to EEPROM
Serial code conversion	SERCODE	Converts sample program data in ROM into serial data and stores it in RAM
Write	WRITE	Transmits serial data of sample program stored in RAM to EEPROM in LSB first
Read	READ	Receives serial data of sample program from EEPROM in LSB first and stores it in RAM
Instruction code conversion	PARCODE	Converts serial data of sample program stored in RAM into instruction code conversion
Received sample program	SPLPGM	Sample program received from EEPROM that repeats turning the LED connected to pin P7 ₃ on or off for each of 262 ms
Error routine	ERROR	Performs error processing

5.2 Arguments

This sample task does not use arguments.

5.3 Internal Registers

The H8/3644 internal registers used in this sample task are described in table 5.2.

Table 5.2 Description of the H8/3644 Internal Registers

Register	Function	Address	Setting	
PDR2	P2 ₁	Port data register 2 (port data register 2 ₁) when P2 ₁ is 0, P2 ₁ pin data is 0 when P2 ₁ is 1, P2 ₁ pin data is 1	H'FFD5 Bit 1	0/1
	P2 ₀	Port data register 2 (port data register 2 ₀) when P2 ₀ is 0, P2 ₀ pin data is 0 when P2 ₀ is 1, P2 ₀ pin data is 1	H'FFD5 Bit 0	0/1
PCR2	PCR2 ₁	Port control register 2 (port control register 2 ₁) when PCR2 ₁ is 0, P2 ₁ pin functions as an input pin when PCR2 ₁ is 1, P2 ₁ pin functions as an output pin	H'FFE5 Bit 1	0/1
	PCR2 ₀	Port control register 2 (port control register 2 ₀) when PCR2 ₀ is 0, P2 ₀ pin functions as an input pin when PCR2 ₀ is 1, P2 ₀ pin functions as an output pin	H'FFE5 Bit 0	0/1
PDR7	P7 ₃	Port data register 7 (port data register 7 ₃) when P7 ₃ is 0, P7 ₃ pin data is 0 when P7 ₃ is 1, P7 ₃ pin data is 1	H'FFDA Bit 3	0/1
PCR7	PCR7 ₃	Port control register 7 (port control register 7 ₃) when PCR7 ₃ is 0, P7 ₃ pin functions as an input pin when PCR7 ₃ is 1, P7 ₃ pin functions as an output pin	H'FFEA Bit 3	1

5.4 Description of RAM

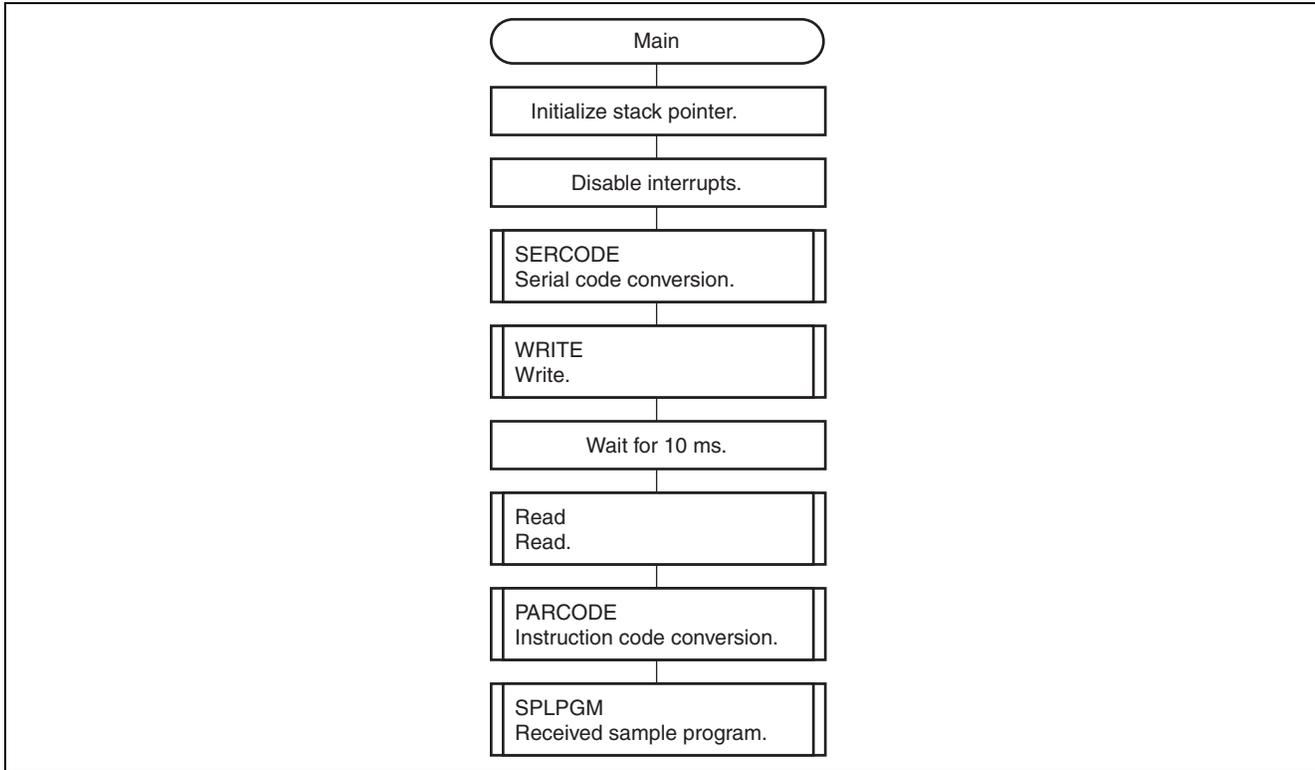
Table 5.3 describes the RAM used in this sample task.

Table 5.3 Description of RAM

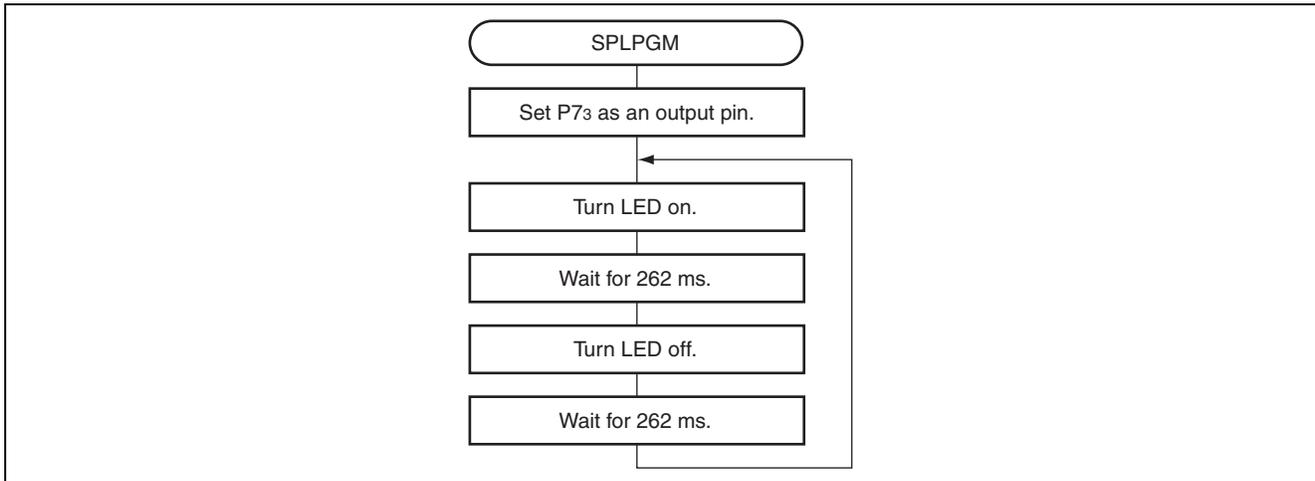
Label	Function	Address	Used in
SERAREA	Stores the start address of RAM to which sample program serial data is stored	H'FB80	Serial code conversion Write Read Instruction code conversion
COUNTER	Stores the last address of RAM to which sample program serial data is stored	H'FEC0	Serial code conversion
SPLPGM	Stores the start address of RAM to which sample program instruction code read from EEPROM is stored	H'FF00	Serial code conversion Instruction code conversion

6. Flowchart

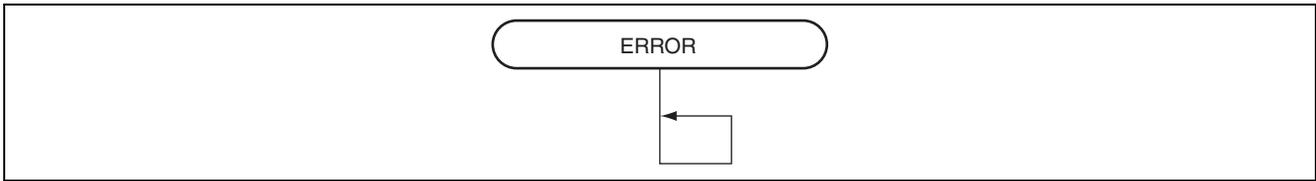
1. Main routine



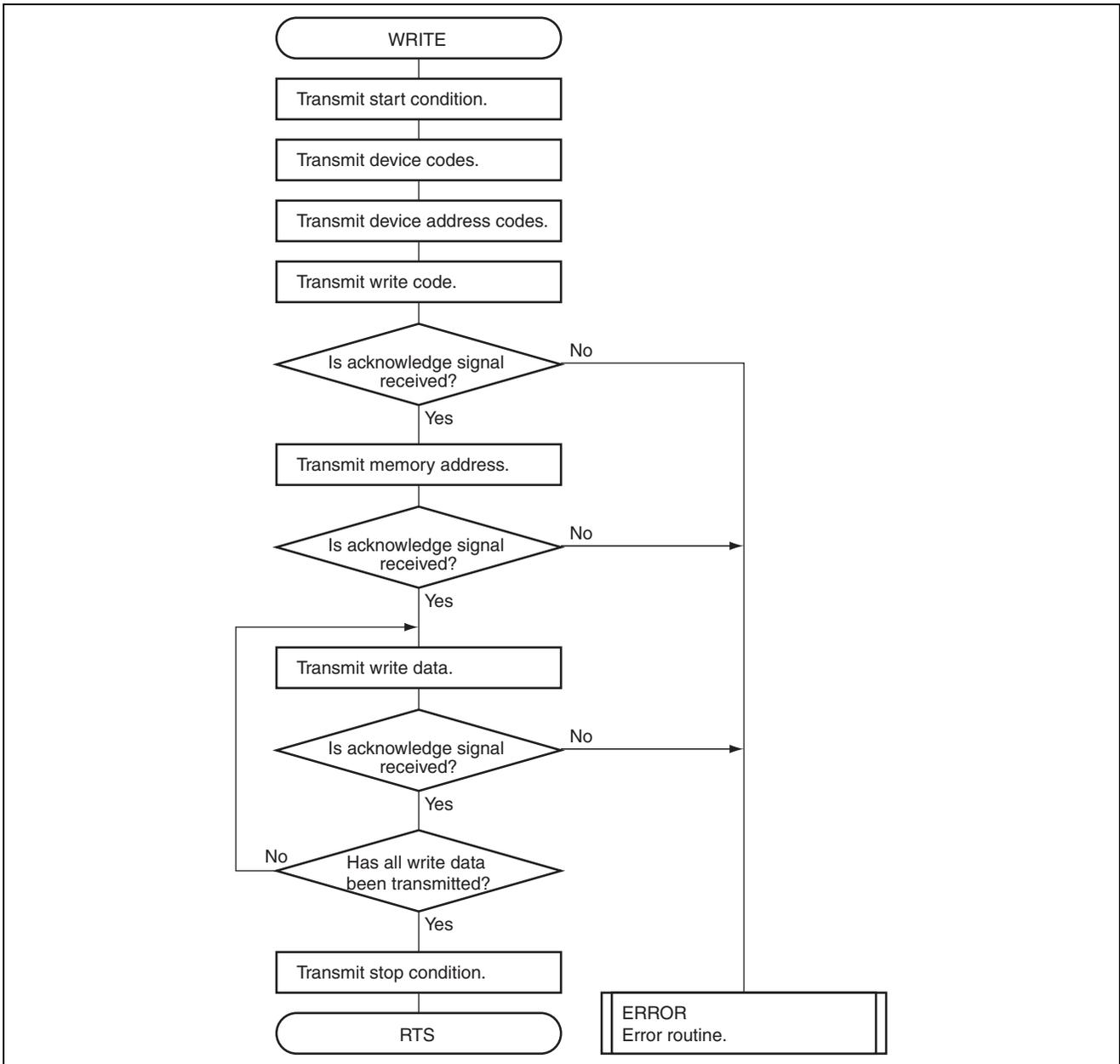
2. Received sample program



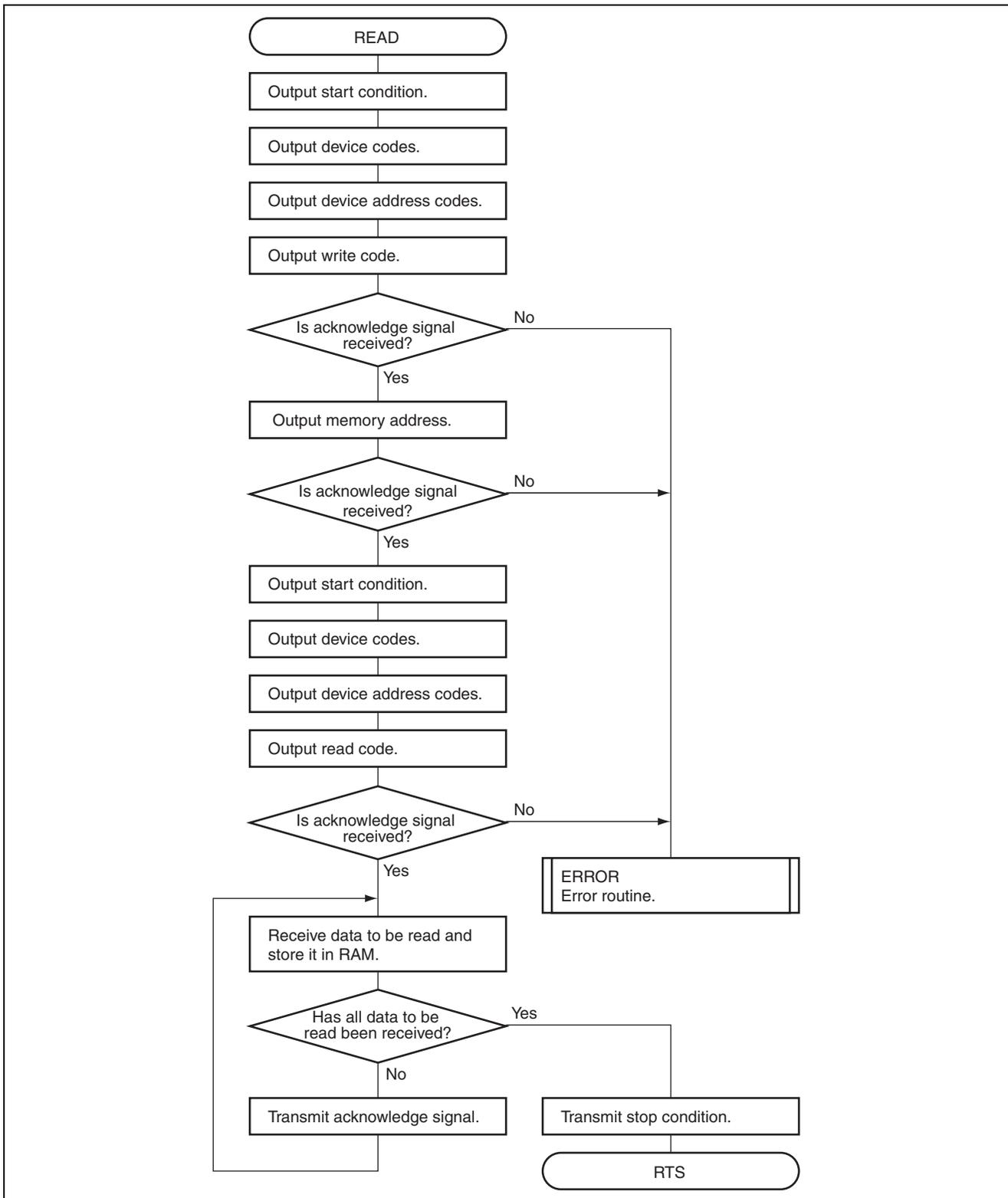
3. Error routine



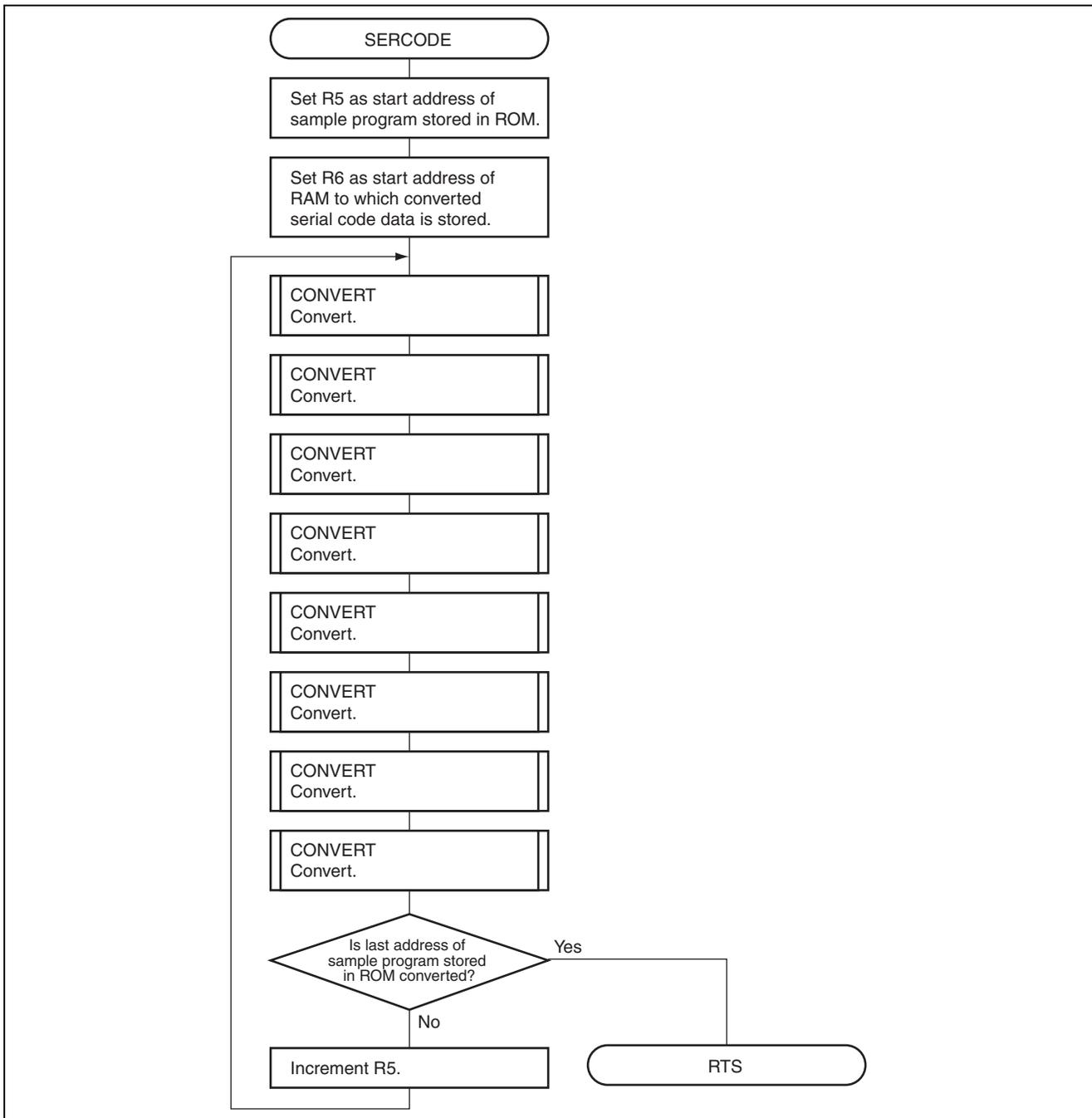
4. Write



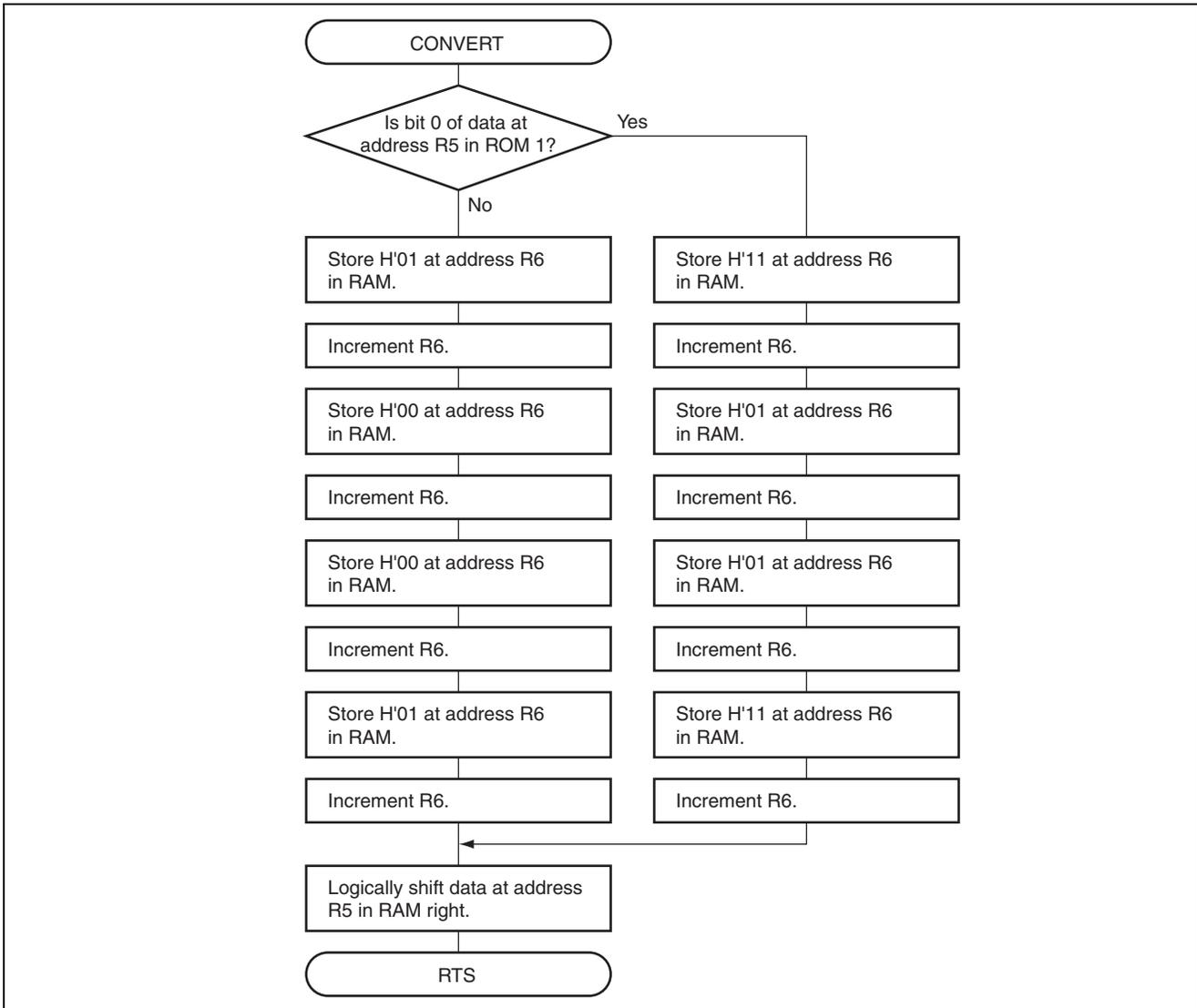
5. Read



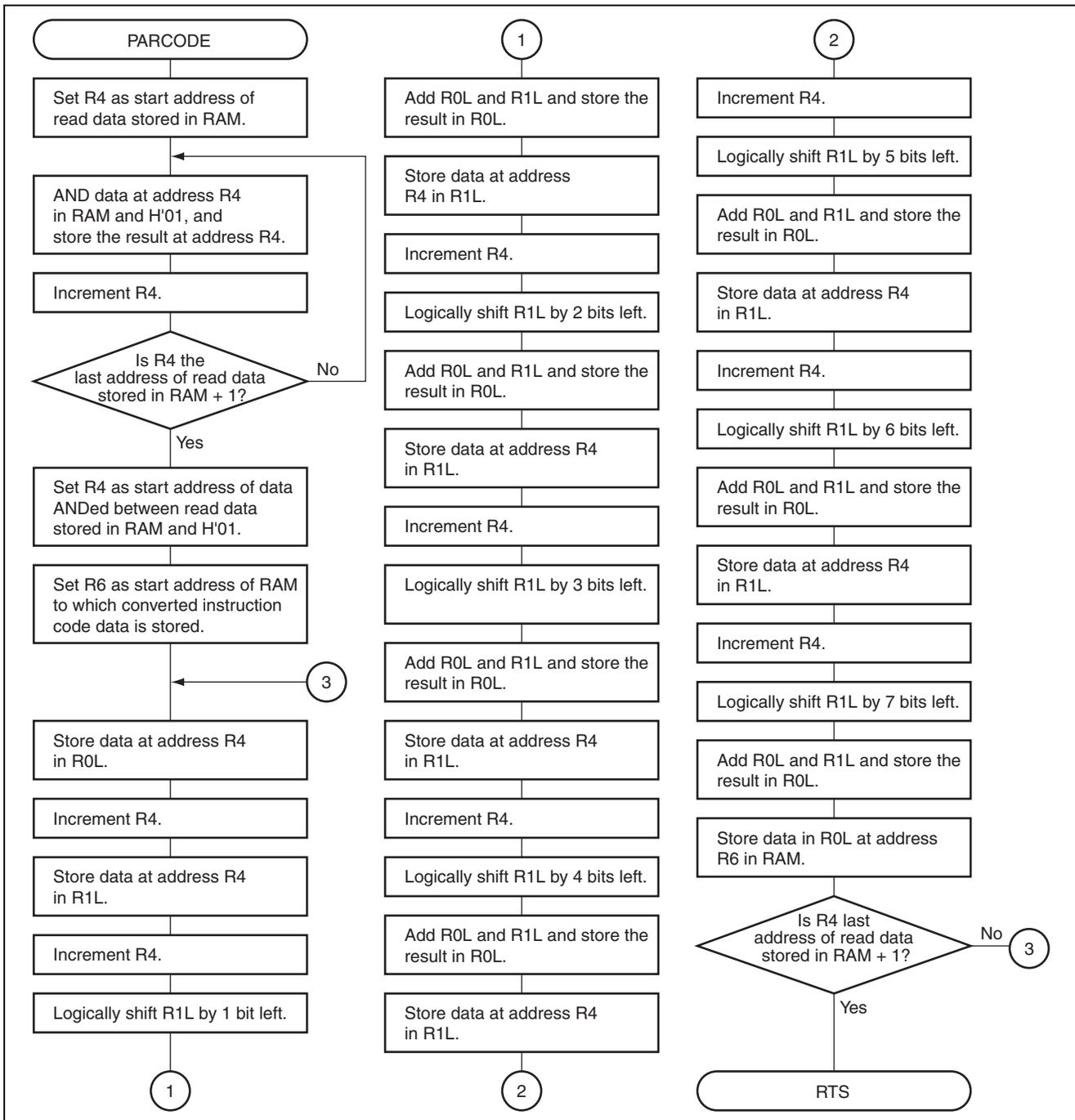
6. Serial code conversion



7. Conversion



8. Instruction code conversion



7. Program Listing

```

;*****
;*
;*      H8/3644 Application Note
;*
;*      'EEPROM Write & Read Control'
;*
;*      Function : I/O Port Base
;*
;*      External Clock : 10MHz
;*      Internal Clock : 5MHz
;*
;*****
;
;      .cpu      300L
;
;*****
;* Symbol Definition
;*****
;
PDR2      .equ      H'FFD5      ;Port Data Register 2
PCR2      .equ      H'FFE5      ;Port Control Register 2
;*****
;* Ram Allocation
;*****
;
SERAREA   .equ      H'FB80      ;Serial code area (H'FB80-H'FEBF: SERSIZE * 4 pulse)
COUNTER   .equ      H'FEC0      ;Counter (@H'FEC0 = H'1A: 26 bytes)
SPLPGM    .equ      H'FF00      ;Sample program area (H'FF00-H'FF19)
STACK     .equ      H'FF80      ;Stack Pointer
SPLSIZE   .equ      H'1A       ;Sample program size ( = 26 bytes)
SERSIZE    .equ      H'D0       ;Serial code size ( = SPLSIZE * 8-bit)
;*****
;* Vector Address
;*****
;
;      .org      H'0000
;      .data.w   MAIN      ;Reset Interrupt
;      .org      H'0008
;      .data.w   MAIN      ;IRQ0 Interrupt
;      .data.w   MAIN      ;IRQ1 Interrupt
;      .data.w   MAIN      ;IRQ2 Interrupt
;      .data.w   MAIN      ;IRQ3 Interrupt
;      .data.w   MAIN      ;INT0 - INT7 Interrupt
;      .data.w   H'0014
;      .data.w   MAIN      ;Timer A Interrupt
;      .data.w   MAIN      ;Timer B1 Interrupt
;      .data.w   H'0020
;      .data.w   MAIN      ;Timer X Interrupt
;      .data.w   MAIN      ;Timer V Interrupt
;      .org      H'0026
;      .data.w   MAIN      ;Sci1 Interrupt
;      .org      H'002A
;      .data.w   MAIN      ;Sci3 Interrupt
;      .data.w   MAIN      ;A/D Converter Interrupt
;      .data.w   MAIN      ;Sleep Interrupt

```

```

;*****
;* Main Program *
;*****
;
;
MAIN      .org          H'1000
MOV.W    #STACK,SP    ;Initialize Stack Pointer
ORC      #H'80,CCR     ;Interrupt Disable
BSR      SERCODE      ;Convert sample program data to serial code
JSR      @WRITE       ;Write EEPROM
MOV.W    #1,R4        ;10ms wait as tWC spec. of EEPROM
MOV.W    #H'208C,R5
TWCWAIT  SUB.W        R4,R5
BNE      TWCWAIT
JSR      @READ        ;Read EEPROM
JSR      @PARCODE     ;Convert Serial code to 8-bit sample program data
MOV.W    #1,R0        ;Load software time data of LED on/off period
MOV.W    #0,R1        ;as 262ms
MOV.W    #1,R2
JMP      @SPLPGM     ;Execute sample program at Internal RAM
;
ERROR     BRA          ERROR    ;ERROR area
;*****
; Convert sample program to serial code *
;*****
;
SERCODE   .equ        $
MOV.B    #0,R0L      ;Load SCL = 1, SDA = 1 data
MOV.B    #1,R1L      ;Load SCL = 1, SDA = 0 data
MOV.B    #2,R2L      ;Load SCL = 0, SDA = 1 data
MOV.B    #3,R3L      ;Load SCL = 0, SDA = 0 data
MOV.W    #SAMPLE,R5  ;Load sample program address
MOV.W    #SERAREA,R6 ;Load serial code address
MOV.B    #SPLSIZE,R4L ;Load sample program size
MOV.B    R4L,@COUNTER
NEXTCON  MOV.B        @R5+,R4L ;Load sample program data
BSR      CONVERT     ;Convert sample program data to serial code bit0
BSR      CONVERT     ;Convert sample program data to serial code bit1
BSR      CONVERT     ;Convert sample program data to serial code bit2
BSR      CONVERT     ;Convert sample program data to serial code bit3
BSR      CONVERT     ;Convert sample program data to serial code bit4
BSR      CONVERT     ;Convert sample program data to serial code bit5
BSR      CONVERT     ;Convert sample program data to serial code bit6
BSR      CONVERT     ;Convert sample program data to serial code bit7
MOV.B    @COUNTER,R4L
DEC      R4L
MOV.B    R4L,@COUNTER
CMP.B    #0,R4L     ;@COUNTER=0?
BNE      NEXTCON    ;No.
RTS
;
;
CONVERT   .equ        $
BTST    #0,R4L      ;If sample program data bitn is "0",
BEQ      BITEQUO    ;it branch to BITEQUO
MOV.B    R2L,@R6    ;Store SCL & SDA data as follows.
ADDS    #1,R6       ;SCL = 0110
MOV.B    R0L,@R6    ;SDA = 1111
ADDS    #1,R6
MOV.B    R0L,@R6
ADDS    #1,R6

```

```

MOV.B      R2L,@R6
ADDS      #1,R6
BRA      BITn
BITEQU0    MOV.B      R3L,@R6      ;Store SCL & SDA data as follows.
ADDS      #1,R6      ;SCL = 0110
MOV.B      R1L,@R6      ;SDA = 0000
ADDS      #1,R6
MOV.B      R1L,@R6
ADDS      #1,R6
MOV.B      R3L,@R6
ADDS      #1,R6
BITn      SHLR      R4L
RTS

;*****
;* Write (Use Page Write Operation) *
;*****
;
WRITE      .equ      $
MOV.B      R0L,@PDR2      ;SCL = "0", SDA = "1"
MOV.B      R2L,@PCR2
;
JSR      @RW_start      ;Output "0" of Device address start bit
JSR      @RW_H      ;Output "1" of Device address
JSR      @RW_L      ;Output "0" of Device address
JSR      @RW_H      ;Output "1" of Device address
JSR      @RW_L      ;Output "0" of Device address
JSR      @RW_L      ;Output "0" of Device address code
JSR      @RW_L      ;Output "0" of Device address code
JSR      @RW_L      ;Output "0" of Device address code
JSR      @RW_L      ;Output "0" of Device address write bit
JSR      @RW_ack      ;Input "0" of /ACK
;
JSR      @RW_L      ;Output "0" of Memory address a7
JSR      @RW_L      ;Output "0" of Memory address a6
JSR      @RW_L      ;Output "0" of Memory address a5
JSR      @RW_L      ;Output "0" of Memory address a4
JSR      @RW_L      ;Output "0" of Memory address a3
JSR      @RW_L      ;Output "0" of Memory address a2
JSR      @RW_L      ;Output "0" of Memory address a1
JSR      @RW_L      ;Output "0" of Memory address a0
JSR      @RW_ack      ;Input "0" of /ACK
;
MOV.W      #SERAREA,R4      ;Load serial code of sample program
MOV.W      #SPLSIZE,R5
WRLOOP     JSR      @WR_data      ;Output Write data D0
JSR      @WR_data      ;Output Write data D1
JSR      @WR_data      ;Output Write data D2
JSR      @WR_data      ;Output Write data D3
JSR      @WR_data      ;Output Write data D4
JSR      @WR_data      ;Output Write data D5
JSR      @WR_data      ;Output Write data D6
JSR      @WR_data      ;Output Write data D7
JSR      @RW_ack      ;Input "0" of /ACK
DEC      R5L      ;Counter=0?
BEQ      WREND      ;No.
BRA      WRLOOP
WREND     JSR      @RW_stop      ;Output stop bit
RTS

```

```

;*****
;* Read (Random & Sequential Operation of EEPROM) *
;*****
;
READ      .equ          $
MOV.W    #SERAREA,R4   ;Load serial code address
MOV.W    #SPLSIZE,R5   ;Load count data ( = 26 bytes)
MOV.B    #0,R0L        ;Load SCL = 1, SDA = 1 data
MOV.B    #1,R1L        ;Load SCL = 1, SDA = 0 data
MOV.B    #2,R2L        ;Load SCL = 0, SDA = 1 data
MOV.B    #3,R3L        ;Load SCL = 0, SDA = 0 data
MOV.B    R0L,@PDR2
MOV.B    R2L,@PCR2     ;SCL = "0", SDA = "1"
;
;
JSR      @RW_start     ;Output "0" of Device address start bit
JSR      @RW_H         ;Output "1" of Device address
JSR      @RW_L         ;Output "0" of Device address
JSR      @RW_H         ;Output "1" of Device address
JSR      @RW_L         ;Output "0" of Device address
JSR      @RW_L         ;Output "0" of Device address code
JSR      @RW_L         ;Output "0" of Device address code
JSR      @RW_L         ;Output "0" of Device address code
JSR      @RW_L         ;Output "0" of Device address write bit
JSR      @RW_ack       ;Input "0" of /ACK
;
;
BSR      RW_L          ;Output "0" of Memory address a7
BSR      RW_L          ;Output "0" of Memory address a6
BSR      RW_L          ;Output "0" of Memory address a5
BSR      RW_L          ;Output "0" of Memory address a4
BSR      RW_L          ;Output "0" of Memory address a3
BSR      RW_L          ;Output "0" of Memory address a2
BSR      RW_L          ;Output "0" of Memory address a1
BSR      RW_L          ;Output "0" of Memory address a0
BSR      RW_ack        ;Input "0" of /ACK
;
;
BSR      RW_start     ;Output "0" of Device address start bit
BSR      RW_H         ;Output "1" of Device address
BSR      RW_L         ;Output "0" of Device address
BSR      RW_H         ;Output "1" of Device address
BSR      RW_L         ;Output "0" of Device address
BSR      RW_L         ;Output "0" of Device address code
BSR      RW_L         ;Output "0" of Device address code
BSR      RW_L         ;Output "0" of Device address code
BSR      RW_H         ;Output "1" of Device address read bit
BSR      RW_ack       ;Input "0" of /ACK
;
;
RDLOOP   JSR          @RD_data   ;Input Read data D0
JSR      @RD_data   ;Input Read data D1
JSR      @RD_data   ;Input Read data D2
JSR      @RD_data   ;Input Read data D3
JSR      @RD_data   ;Input Read data D4
JSR      @RD_data   ;Input Read data D5
JSR      @RD_data   ;Input Read data D6
JSR      @RD_data   ;Input Read data D7
BSR      RW_L       ;Output "0" of /ACK bit
DEC      R5L
BEQ      SERDEND
BRA     RDLOOP

```

```

SERDEND .equ      $
        MOV.B    R0L,@PDR2
        MOV.B    R3L,@PCR2      ;SCL = "0", SDA = "0"
        BSR      RW_stop      ;Output stop bit
        RTS

;*****
; Subroutine *
;*****
;
RW_start .equ     $
        MOV.B    R0L,@PDR2      ;Output "0" of Start bit
        MOV.B    R2L,@PCR2      ;SCL = "0", SDA = "1"
        MOV.B    R0L,@PDR2
        MOV.B    R0L,@PCR2      ;SCL = "1", SDA = "1"
        MOV.B    R0L,@PDR2
        MOV.B    R1L,@PCR2      ;SCL = "1", SDA = "0"
        MOV.B    R0L,@PDR2
        MOV.B    R3L,@PCR2      ;SCL = "0", SDA = "0"
        RTS

;
RW_H .equ        $
        MOV.B    R0L,@PDR2      ;Output "1" of Device/Memory address
        MOV.B    R2L,@PCR2      ;SCL = "0", SDA = "1"
        MOV.B    R0L,@PDR2
        MOV.B    R0L,@PCR2      ;SCL = "1", SDA = "1"
        MOV.B    R0L,@PDR2
        MOV.B    R0L,@PCR2      ;SCL = "1", SDA = "1"
        MOV.B    R0L,@PDR2
        MOV.B    R2L,@PCR2      ;SCL = "0", SDA = "1"
        RTS

;
RW_L .equ        $
        MOV.B    R0L,@PDR2      ;Output "0" of Device/Memory address or /ACK
        MOV.B    R3L,@PCR2      ;SCL = "0", SDA = "0"
        MOV.B    R0L,@PDR2
        MOV.B    R1L,@PCR2      ;SCL = "1", SDA = "0"
        MOV.B    R0L,@PDR2
        MOV.B    R1L,@PCR2      ;SCL = "1", SDA = "0"
        MOV.B    R0L,@PDR2
        MOV.B    R3L,@PCR2      ;SCL = "0", SDA = "0"
        RTS

;
RW_ack .equ      $
        MOV.B    R0L,@PDR2      ;Input "0" of /ACK bit
        MOV.B    R2L,@PCR2
        MOV.B    R0L,@PDR2
        MOV.B    R0L,@PCR2
        BTST     #0,@PDR2      ;/ACK=0?
        BEQ      ACKOK          ;Yes.
        JMP      @ERROR
ACKOK .equ       $
        MOV.B    R0L,@PDR2
        MOV.B    R3L,@PCR2      ;SCL = "0", SDA = "0"
        RTS

;

```

```

RW_stop    .equ          $
            MOV.B        R0L,@PDR2    ;Output "1" of Stop bit
            MOV.B        R1L,@PCR2    ;SCL = "1", SDA = "0"
            MOV.B        R0L,@PDR2
            MOV.B        R0L,@PCR2    ;SCL = "1", SDA = "1"
            MOV.B        R0L,@PDR2
            MOV.B        R2L,@PCR2    ;SCL = "0", SDA = "1"
            MOV.B        R0L,@PDR2
            MOV.B        R2L,@PCR2    ;SCL = "0", SDA = "1"
            MOV.B        R0L,@PDR2
            MOV.B        R0L,@PCR2    ;SCL = "1", SDA = "1"
            RTS

;
WR_data    .equ          $
            MOV.B        @R4+,R1L     ;Output write data bitn
            MOV.B        R1L,@PCR2    ;SCL = "0", SDA = "Dn Output"
            MOV.B        @R4+,R1L
            MOV.B        R1L,@PCR2    ;SCL = "1", SDA = "Dn Output"
            MOV.B        @R4+,R1L
            MOV.B        R1L,@PCR2    ;SCL = "1", SDA = "Dn Output"
            MOV.B        @R4+,R1L
            MOV.B        R1L,@PCR2    ;SCL = "0", SDA = "Dn Output"
            RTS

;
RD_data    .equ          $
            MOV.B        R0L,@PDR2    ;Input read data bitn
            MOV.B        R2L,@PCR2    ;SCL = "0", SDA = "Dn input"
            MOV.B        R0L,@PDR2
            MOV.B        R0L,@PCR2    ;SCL = "1", SDA = "Dn input"
            MOV.B        @PDR2,R6L
            MOV.B        R6L,@R4      ;Store serial code at Internal RAM
            ADDS         #1,R4
            MOV.B        R0L,@PDR2
            MOV.B        R2L,@PCR2    ;SCL = "0", SDA = "Dn input"
            RTS

;
PARCODE    .equ          $
            MOV.W        #SERAREA,R4  ;Load serial code address
            MOV.B        #SERSIZE,R5L
ANDDATA    MOV.B        @R4,R0L       ;AND.B #1,@SERAREA(H'FB80-FEBF)
            AND          #H'01,R0L
            MOV.B        R0L,@R4
            ADDS         #1,R4
            DEC          R5L
            BNE          ANDDATA
            MOV.W        #SERAREA,R4  ;Load serial code address
            MOV.W        #SPLSIZE,R5
            MOV.W        #SPLPGM,R6   ;Load execution sample program address
SERPAR     MOV.B        @R4+,R0L      ;Load serial code bit0
            MOV.B        @R4+,R1L      ;Load serial code bit1
            SHLL         R1L           ;Convert bit1 code
            ADD.B        R1L,R0L       ;Calculate Bit1,0 code
            MOV.B        @R4+,R1L      ;Load serial code bit2
            SHLL         R1L           ;Convert bit2 code
            SHLL         R1L
            ADD.B        R1L,R0L       ;Calculate Bit2-0 code
            MOV.B        @R4+,R1L      ;Load serial code bit3
            SHLL         R1L           ;Convert bit3 code
            SHLL         R1L

```

```

SHLL      R1L
ADD.B    R1L,R0L      ;Calculate Bit3-0 code
MOV.B    @R4+,R1L    ;Load serial code bit4
SHLL      R1L        ;Convert bit4 code
SHLL      R1L
SHLL      R1L
SHLL      R1L
ADD.B    R1L,R0L      ;Calculate Bit4-0 code
MOV.B    @R4+,R1L    ;Load serial code bit5
SHLL      R1L        ;Convert bit5 code
SHLL      R1L
SHLL      R1L
SHLL      R1L
SHLL      R1L
ADD.B    R1L,R0L      ;Calculate Bit5-0 code
MOV.B    @R4+,R1L    ;Load serial code bit6
SHLL      R1L        ;Convert bit6 code
SHLL      R1L
SHLL      R1L
SHLL      R1L
SHLL      R1L
SHLL      R1L
ADD.B    R1L,R0L      ;Calculate Bit6-0 code
MOV.B    @R4+,R1L    ;Load serial code bit7
SHLL      R1L        ;Convert bit7 code
SHLL      R1L
SHLL      R1L
SHLL      R1L
SHLL      R1L
SHLL      R1L
ADD.B    R1L,R0L      ;Calculate Bit7-0 code
MOV.B    R0L,@R6
ADDS     #1,R6
DEC      R5L
BNE      SERPAR
RTS

;*****
;* H8/3644 Sample program of LED Control *
;*****
;
        .org      H'2000
SAMPLE  BSET     #3,@H'FFEA      ;Initialize P73 Output Port
LEDCTL  BSET     #3,@H'FFDA      ;Turn on LED
        BSR      WAIT
        BCLR     #3,@H'FFDA      ;Turn off LED
        BSR      WAIT
        BRA     LEDCTL
WAIT    SUB.W    R0,R1
        MULXU   R0L,R2
        BNE     WAIT
        RTS

;
        .end

```

Revision Record

Rev.	Date	Description	
		Page	Summary
1.00	Dec.19.03	—	First edition issued

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